

Figure 2. Crossing pattern. (a) When the distance λ between ridges on a sapphire substrate (pink) exceeds the preferred spacing L_1 of cylindrical microdomains (red) in an overlying polymer film, the bottommost microdomains align normal to the ridges to minimize free energy. **(b)** A second layer of microdomains, guided into place by the first, then forms a well-ordered array. (Adapted from ref. 2.)

marred by defects.

Sampling various locations on a roughly centimeter-sized sample of the nanopatterned film, the team found that the orientation of the ordered cylindrical domains rarely deviates by more than 1° from the mean. Also, grazing-incidence scattering experiments showed distinct Bragg diffraction of x-ray beams incident along the microdomain direction, which suggests that the material's longrange order is essentially crystalline. Says MIT's Caroline Ross, "It's probably the best-ordered pattern one can imagine making with block copolymers."

In a display of the technique's versa-

tility, Russell and his colleagues demonstrated that a plastic replica of the nanofaceted sapphire surface performs just fine as a surrogate substrate; the cylindrical domains align as perfectly on the replica as they do on the sapphire. The researchers have also demonstrated that the nanopattern itself can be used to imprint a plastic mold, which could, in turn, serve as a master template in a roll-to-roll printing scheme.

More room at the bottom

Ross thinks the ordered nanopatterns could be useful as extreme-UV or x-ray diffraction gratings. Russell envisions converting them into nanowire arrays or ultradense magnetic storage devices. The patterns' 30-nm features are already as small as the tiniest features that can be created with photolithography. Can they be made smaller still?

It's certainly possible to further miniaturize the polymer microdomains. That's simply a matter of constructing shorter polymer chains. However, as the microdomain length scale shrinks with respect to the ridge spacing of the nanofaceted surface—that is, as L_1 becomes much smaller than λ orientation effects become less important, and so the driving force for microdomain alignment diminishes. Still, Russell is optimistic that his team's strategy can be used to create ordered patterns with features as small as 3 nm. Ît's left to future experiments to prove whether he's right.

Ashley G. Smart

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Frequency-doubled photons can measure current density

The possibility, anticipated theoretically 16 years ago, could be applied as a semiconductor diagnostic.

The field of nonlinear optics was born in 1961, when Peter Franken and colleagues at the University of Michigan shot red light at a quartz crystal and measured near-UV light exiting out the back.¹ Within a year a team of scientists at the Ford Motor Co had experimentally demonstrated that frequency doubling, or second-harmonic

generation (SHG), could be induced by an externally applied electric field.² Nowadays, physicists routinely use SHG to measure electric fields in semiconductor devices. The fields serve to diagnose any number of properties—for example, how ambient oxygen affects the ability of a thin silicon oxide layer to trap electrons.

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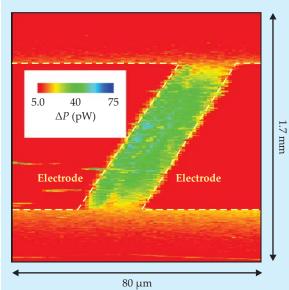


Figure 1. The power ΔP in frequency-doubled light serves as a measure of the current density in a semiconductor. In this image, the green area identifies the current flowing between two gold electrodes affixed atop a gallium arsenide crystal. The red background is a consequence of electronic noise and stray light. (Adapted from ref. 5.)

Johns Hopkins University theorist Jacob Khurgin began to compose a variation on the field-as-diagnostic theme in 1995, when he calculated that electric current also can induce SHG.3 As a consequence, he predicted, it should be possible to probe the current in a semiconductor via a measurement of its outgoing frequency-doubled light. Khurgin's principal result was confirmed in 2009, when Oleg Aktsipetrov (Moscow State University) and colleagues measured the frequency-doubled light generated when light bounces off a current-carrying silicon crystal.4 The Aktsipetrov group, though, did not map out current density in detail. That challenge has now been realized by Hui Zhao (University of Kansas), his student Brian Ruzicka, and an international team that includes Khurgin.⁵ Their methods, says Zhao, should enable current-based diagnostics that complement present techniques relying on field-induced SHG.

Current thinking

In their simplest experiment, Zhao and colleagues mapped the direct current flowing through a room-temperature gallium arsenide sample to which two gold electrodes had been affixed. The first step was to establish, as theoretically expected and independently seen by Aktsipetrov and company, that the power in frequency-doubled light is proportional to current density. To do

they passed known currents across the electrodes and interrogated the sample with a pulsed 1800-nm laser beam polarized in the direction of the current. The interrogating beam was focused on a 4-µm-diameter spot between the electrodes, and the transmitted 900-nm light was detected with a silicon photodiode.

Current was not the only source of the observed frequency-doubled light. Like quartz, GaAs crystals can intrinsically induce SHG. The Kansas researchers, in essence, measured the power in 900-nm light with and without current flow and confirmed that the difference is proportional to current den-

sity. Once that linear relation was established, they could map out current by scanning the laser focus across the GaAs sample.

Figure 1 shows the result. The green swath gives the power at 900 nm due to the current flowing left to right between the electrodes. Although the direct current measured by Zhao and colleagues is accompanied by an Ohm's-law electric field that itself generates frequency doubling, theoretical considerations show that the observed frequency doubling is indeed current induced, not field induced. Moreover, the researchers followed their DC experiment with one in

which frequency-doubled radiation measured an oscillating current created via a procedure called coherent current injection. That technique exploits quantum interference to produce current without requiring any external electric field.

You can't go Ohm again

In coherent current injection, two indistinguishable processes promote electrons from the valence to the conduction band; figure 2 sketches the idea. One process involves the absorption of a single laser photon at frequency 2ω ; the second requires that two laser photons at frequency ω be absorbed. The quantum amplitude for the promotion is a sum of the amplitudes for the two individual processes. The probability, therefore, includes an interference term, which depends on the momentum of the electron being promoted and also on a phase parameter, the phase of the beam at 2ω minus twice the phase of the beam at ω .

When the phase parameter is zero, electrons with momentum $\hbar k$ and those with momentum $-\hbar k$ are promoted with equal likelihood; no current flows. But as Zhao and colleagues change the phase parameter by adjusting the relative path length of their two pumping laser beams, they alternate between preferentially promoting electrons with positive momentum (leaving holes with negative momentum) and promoting electrons with negative momentum. In either case, the nontrivial phase relations lead to the initiation of a net current parallel to the polarization of the pumping lasers.

Once electrons and holes are injected with opposite momenta, they begin to separate. But Coulomb attraction decelerates them, stops them, and draws them together. The result is a rapidly

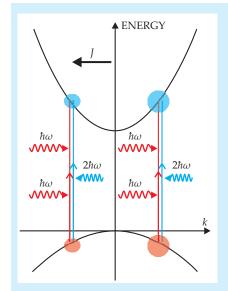


Figure 2. Coherent current injection relies on the interference between two processes that promote electrons to the conduction band. One involves the absorption of a single photon with an energy $2\hbar\omega$, sufficient to promote the electron; the second requires the absorption of two photons with half that energy. When laser beams providing the photons are suitably out of phase, electrons with positive momentum $\hbar k$ are preferentially promoted, as schematically indicated by the larger filled circles on the right. As a result, current density *J* flows in the negative direction. (Adapted from ref. 5.)

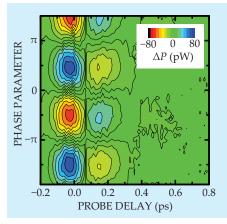


Figure 3. Current oscillations reveal themselves by the frequency-doubled light they induce. In this plot, the phase parameter, as described in the text, determines the initial amplitude and direction of the current. For a fixed phase, the current-induced power ΔP in frequency-doubled light oscillates as a function of time between current injection and second-harmonic generation. Both the lasers that inject current and the laser that triggers SHG have finite pulse widths. For that reason, current is observed even before the nominal injection time t=0. (Adapted from ref. 5.)

oscillating plasma current, strongly damped because the charge flow occurs in a material medium. To measure it, Zhao and company observed the enhanced power in the frequencydoubled light, essentially just as they did in the DC case. In this more dynamic context, however, they did not map out current density as a function of position. Rather, they focused the interrogating laser beam on a fixed, 2.1-µmdiameter spot on the GaAs sample, but varied the time interval separating the injection of current by the pump lasers and the observation of SHG triggered by the interrogating laser. As figure 3 shows, the researchers observed a plasma oscillation period of about 0.4 ps (a half-cycle is readily apparent). Follow-up trials established that the oscillation amplitude depends on the angle between the current and the interrogating beam's polarization; it's greatest when the two are parallel. If the direction of current flow is unknown, one can determine it by finding the polarization that gives the maximum power in frequency-doubled light.

Admittedly, the separated electrons and holes affect the other charges in the GaAs, and so the sample is permeated with an electric field capable of inducing SHG. Intuitively, though, one might expect that the internal electric field would lag behind the inducing current. And indeed, experiments show the lag to be about a quarter period. The ob-

served coincidence of current injection and maximum power in frequencydoubled light demonstrates that the SHG is induced by the current rather than by the field.

The 50-fs time resolution already achieved by his group, says Zhao, is superior to that of other currentmeasuring techniques and should enable studies of transient electron transport in graphene, carbon nanotubes, and other nanomaterials too small to support steady currents. Moreover, it can easily be improved with the help of shorterpulsed lasers. Near-field optics may enable the team to improve its spatial resolution from 2 µm to about 100 nm. Even that superior resolution is not as good as could be obtained with, for example, electron microscopy. But current measurements via SHG and coherent current injection allow for the study of samples in situ. There's no need to alter them by attaching electrodes or to destroy them with high-energy electrons.

Steven K. Blau

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